### INTEGRATED CIRCUITS

# DATA SHEET

# 74LVT16240A

3.3 V LVT 16-bit inverting buffer/driver (3-State)

Product data Supersedes data of 1998 Feb 19





# 3.3 V 16-bit inverting buffer/driver (3-State)

### 74LVT16240A

#### **FEATURES**

- 16-bit bus interface
- 3-State buffers
- Output capability: +64 mA/-32 mA
- TTL input and output switching levels
- Input and output interface capability to systems at 5 V supply
- Bus-hold data inputs eliminate the need for external pull-up resistors to hold unused inputs
- Live insertion/extraction permitted
- Power-up 3-State
- No bus current loading when output is tied to 5 V bus
- Latch-up protection exceeds 500 mA per JEDEC Std 17
- ESD protection exceeds 2000 V per MIL STD 883 Method 3015 and 200 V per Machine Model

#### **DESCRIPTION**

The 74LVT16240A is a high-performance BiCMOS product designed for  $V_{CC}$  operation at 3.3 V.

This device is an inverting 16-bit buffer that is ideal for driving bus lines. The device features four Output Enables ( $1\overline{OE}$ ,  $2\overline{OE}$ ,  $3\overline{OE}$ ,  $4\overline{OE}$ ), each controlling four of the 3-State outputs.

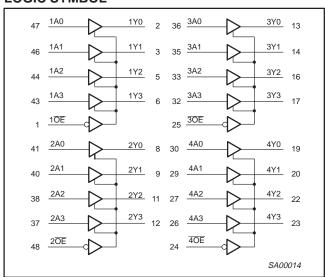
#### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS T <sub>amb</sub> = 25 °C	TYPICAL	UNIT
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay nAx to n∀x	$C_L = 50 \text{ pF};$ $V_{CC} = 3.3 \text{ V}$	1.9	ns
C <sub>IN</sub>	Input capacitance nOE	V <sub>I</sub> = 0 V or 3.0 V	3	pF
C <sub>OUT</sub>	Output capacitance	Outputs disabled; V <sub>O</sub> = 0 V or 3.0 V	9	pF
I <sub>CCZ</sub>	Total supply current	Outputs disabled; V <sub>CC</sub> = 3.6 V	70	μΑ

#### ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	PART NUMBER	DWG NUMBER		
48-Pin Plastic SSOP Type III	–40 °C to +85 °C	74LVT16240ADL	SOT370-1		
48-Pin Plastic TSSOP Type II	–40 °C to +85 °C	74LVT16240ADGG	SOT362-1		

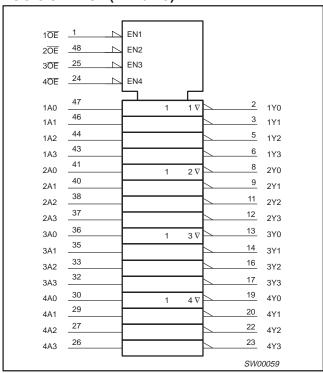
#### **LOGIC SYMBOL**



# 3.3 V 16-bit inverting buffer/driver (3-State)

### 74LVT16240A

### LOGIC SYMBOL (IEEE/IEC)



#### **FUNCTION TABLE**

Inp	uts	Outputs
nOE	nAx	n₹x
L	L	Н
L	Н	L
Н	Х	Z

H = HIGH voltage level

L = LOW voltage level

X = Don't care

Z = High Impedance "off" state

#### **PIN CONFIGURATION**

10E 1 11V0 2 17V1 3 148 20E 11V1 3 46 1A1 11V1 3 46 1A1 11V2 5 44 1A2 11V3 6 43 1A3 11V3 6 43 1A3 11V3 6 44 1A2 11V3 6 45 GND 10 2 Y0 8 41 2A0 2 Y1 9 40 2A1 10 39 GND 2 Y2 11 38 2A2 2 Y3 12 3 7 2A3 3 Y0 13 3 36 3A0 3 Y1 14 3 35 3A1 3 GND
1Y0 2 1Y1 3 46 1A1 GND 4 45 GND 1Y2 5 44 1A2 1Y3 6 43 1A3 VCC 7 42 VCC 2Y0 8 41 2A0 2Y1 9 40 2A1 GND 10 39 GND 2Y2 11 38 2A2 2Y3 12 37 2A3 3Y0 13 3Y1 14 GND 15 34 GND
1Y1 3 46 1A1 GND 4 45 GND 1Y2 5 44 1A2 1Y3 6 43 1A3 VCC 7 42 VCC 2Y0 8 41 2A0 2Y1 9 40 2A1 GND 10 39 GND 2Y2 11 38 2A2 2Y3 12 37 2A3 3Y0 13 36 3A0 3Y1 14 35 3A1 GND 15 34 GND
GND 4 45 GND  1Y2 5 44 1A2  1Y3 6 43 1A3  VCC 7 42 VCC  2Y0 8 41 2A0  2Y1 9 40 2A1  GND 10 39 GND  2Y2 11 38 2A2  2Y3 12 37 2A3  3Y0 13 36 3A0  3Y1 14 35 3A1  GND 15 34 GND
1Y2 5 44 1A2 1Y3 6 43 1A3  VCC 7 42 VCC 2Y0 8 41 2A0 2Y1 9 40 2A1 GND 10 39 GND 2Y2 11 38 2A2 2Y3 12 37 2A3 3Y0 13 36 3A0 3Y1 14 35 3A1 GND 15 34 GND
1Y3 6 43 1A3  VCC 7 42 VCC  2Y0 8 41 2A0  2Y1 9 40 2A1  GND 10 39 GND  2Y2 11 38 2A2  2Y3 12 37 2A3  3Y0 13 36 3A0  3Y1 14 35 3A1  GND 15 34 GND
VCC 7 2Y0 8 41 2A0 2Y1 9 40 2A1 GND 10 39 GND 2Y2 11 38 2A2 2Y3 12 37 2A3 3Y0 13 36 3A0 3Y1 14 GND 15 34 GND
2Y0 8 41 2A0 2Y1 9 40 2A1 GND 10 39 GND 2Y2 111 38 2A2 2Y3 12 37 2A3 3Y0 13 36 3A0 3Y1 14 35 3A1 GND 15 34 GND
2Y0 8 41 2A0 2Y1 9 40 2A1 GND 10 39 GND 2Y2 11 38 2A2 2Y3 12 37 2A3 3Y0 13 36 3A0 3Y1 14 35 3A1 GND 15 34 GND
GND 10 39 GND 2Y2 11 38 2A2 2Y3 12 37 2A3 3Y0 13 36 3A0 3Y1 14 35 3A1 GND 15 34 GND
2Y2 11 38 2A2 2Y3 12 37 2A3 3Y0 13 36 3A0 3Y1 14 35 3A1 GND 15 34 GND
2Y3 12 37 2A3 3Y0 13 36 3A0 3Y1 14 35 3A1 GND 15 34 GND
3Y0 13 36 3A0 3Y1 14 35 3A1 GND 15 34 GND
3Y1 14 35 3A1 GND 15 34 GND
GND 15 34 GND
3Y2 16 33 3A2
3Y4 17 32 3A3
V <sub>CC</sub> 18 31 V <sub>CC</sub>
4Y0 19 30 4A0
4Y1 20 29 4A1
GND 21 28 GND
4Y2 22 27 4A2
4Y3 23 26 4A3
4OE   24   25   3OE
SA00013

#### **PIN DESCRIPTION**

PIN NUMBER	SYMBOL	NAME AND FUNCTION
47, 46, 44, 43, 41, 40, 38, 37, 36, 35, 33, 32, 30, 29, 27, 26	1A0-1A3 2A0-2A3 3A0-3A3 4A0-4A3	Data inputs
2, 3, 5, 6, 8, 9, 11, 12, 13, 14, 16, 17, 19, 20, 22, 23	1 <u>7</u> 0-1 <u>7</u> 3 2 <u>7</u> 0-2 <u>7</u> 3 3 <u>7</u> 0-3 <u>7</u> 3 4 <u>7</u> 0-4 <u>7</u> 3	Data outputs
1, 48, 25, 24	10E, 20E, 30E, 40E	Output Enables
4, 10, 15, 21, 28, 34, 39, 45	GND	Ground (0 V)
7, 18, 31, 42	V <sub>CC</sub>	Positive supply voltage

# 3.3 V 16-bit inverting buffer/driver (3-State)

74LVT16240A

#### ABSOLUTE MAXIMUM RATINGS1, 2

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V <sub>CC</sub>	DC supply voltage		-0.5 to +4.6	V
I <sub>IK</sub>	DC input diode current	V <sub>I</sub> < 0 V	-50	mA
V <sub>I</sub>	DC input voltage <sup>3</sup>		-0.5 to +7.0	V
I <sub>OK</sub>	DC output diode current	V <sub>O</sub> < 0 V	-50	mA
V <sub>OUT</sub>	DC output voltage <sup>3</sup>	Output in Off or HIGH state	-0.5 to +7.0	V
	DC output ourrest	Output in LOW state		A
Гоит	DC output current	Output in HIGH state	-64	mA
T <sub>stg</sub>	Storage temperature range		-65 to +150	°C

#### NOTES:

#### **RECOMMENDED OPERATING CONDITIONS**

SYMBOL	PARAMETER	LIM	ITS	UNIT
STWIBUL	PARAMETER	MIN	MAX	UNII
V <sub>CC</sub>	DC supply voltage	2.7	3.6	V
$V_{I}$	Input voltage	0	5.5	V
$V_{IH}$	HIGH-level input voltage	2.0		V
$V_{IL}$	Input voltage		0.8	V
I <sub>OH</sub>	HIGH-level output current		-32	mA
I <sub>OL</sub>	LOW-level output current		32	mA
	LOW-level output current; current duty cycle ≤ 50%; f ≥ 1 kHz		64	1
Δt/Δν	Input transition rise or fall rate; Outputs enabled		10	ns/V
T <sub>amb</sub>	Operating free-air temperature range	-40	+85	°C

<sup>1.</sup> Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

<sup>2.</sup> The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150 °C.

<sup>3.</sup> The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

# 3.3 V 16-bit inverting buffer/driver (3-State)

### 74LVT16240A

#### DC ELECTRICAL CHARACTERISTICS

			1	ĺ			
SYMBOL	PARAMETER	T <sub>amb</sub> = -4	UNIT				
				MIN	TYP <sup>1</sup>	MAX	1
V <sub>IK</sub>	Input clamp voltage	$V_{CC} = 2.7 \text{ V; } I_{IK} = -18 \text{ mA}$			-0.85	1.2	٧
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V; } I_{OH} = -100 \mu\text{A}$		V <sub>CC</sub> -0.2	V <sub>CC</sub>		
$V_{OH}$	HIGH-level output voltage	V <sub>CC</sub> = 2.7 V; I <sub>OH</sub> = -8 mA		2.4	2.5		V
		$V_{CC} = 3.0 \text{ V; } I_{OH} = -32 \text{ mA}$		2.0	2.3		
		V <sub>CC</sub> = 2.7 V; I <sub>OL</sub> = 100 μA			0.07	0.2	
		V <sub>CC</sub> = 2.7 V; I <sub>OL</sub> = 24 mA			0.03	0.5	
$V_{OL}$	LOW-level output voltage	V <sub>CC</sub> = 3.0 V; I <sub>OL</sub> = 16 mA			0.25	0.4	V
		V <sub>CC</sub> = 3.0 V; I <sub>OL</sub> = 32 mA		0.30	0.5		
		V <sub>CC</sub> = 3.0 V; I <sub>OL</sub> = 64 mA			0.40	0.55	
		$V_{CC} = 3.6 \text{ V}; V_I = V_{CC} \text{ or GND}$	Control pins		0.1	±1.0	μΑ
		V <sub>CC</sub> = 0 V or 3.6 V; V <sub>I</sub> = 5.5 V			0.4	10	
11	Input leakage current	V <sub>CC</sub> = 3.6 V; V <sub>I</sub> = V <sub>CC</sub>	<b>-</b>		0.1	1	
		V <sub>CC</sub> = 3.6 V; V <sub>I</sub> = 0 V	Data pins <sup>4</sup>		-0.4	<b>-</b> 5	
I <sub>OFF</sub>	Output off current	$V_{CC} = 0 \text{ V}; V_{I} \text{ or } V_{O} = 0 \text{ V to } 4.5 \text{ V}$	•		0.1	±100	μΑ
		V <sub>CC</sub> = 3 V; V <sub>I</sub> = 0.8 V		75	135		μΑ
$I_{HOLD}$	Bus Hold current A inputs <sup>6</sup>	V <sub>CC</sub> = 3 V; V <sub>I</sub> = 2.0 V		-75	-135		
		V <sub>CC</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 3.6 V		±500			
I <sub>EX</sub>	Current into an output in the HIGH state when V <sub>O</sub> > V <sub>CC</sub>	V <sub>O</sub> = 5.5 V; V <sub>CC</sub> = 3.0 V			50	125	μА
I <sub>PU/PD</sub>	Power-up/-down 3-State output current <sup>3</sup>	$V_{CC} \le 1.2 \text{ V}; V_O = 0.5 \text{ V to } V_{CC}; V_I = GNOE/OE = Don't care$	ND or V <sub>CC</sub>		1	±100	μА
I <sub>OZH</sub>	3-State output HIGH current	$V_{CC} = 3.6 \text{ V}; V_O = 3.0 \text{ V}; V_I = V_{IL} \text{ or } V_{IH}$			0.5	5	
I <sub>OZL</sub>	3-State output LOW current	$V_{CC} = 3.6 \text{ V}; V_O = 0.5 \text{ V}; V_I = V_{IL} \text{ or } V_{IH}$			0.5	<b>-</b> 5	μΑ
I <sub>CCH</sub>		$V_{CC} = 3.6 \text{ V}$ ; Outputs High, $V_I = \text{GND or}$		0.07	0.12	mA	
I <sub>CCL</sub>	Quiescent supply current	$V_{CC} = 3.6 \text{ V}$ ; Outputs Low, $V_I = \text{GND or}$		4.0	6.0		
I <sub>CCZ</sub>		$V_{CC} = 3.6 \text{ V}$ ; Outputs Disabled; $V_{I} = \text{GND or } V_{CC, I_{O}} = 0^{5}$			0.07	0.12	
Δl <sub>CC</sub>	Additional supply current per input pin <sup>2</sup>	$V_{CC}$ = 3V to 3.6V; One input at $V_{CC}$ -0.6 Other inputs at $V_{CC}$ or GND	SV,		0.1	0.20	mA

- All typical values are at V<sub>CC</sub> = 3.3 V and T<sub>amb</sub> = 25 °C.
   This is the increase in supply current for each input at the specified voltage level other than V<sub>CC</sub> or GND.
   This parameter is valid for any V<sub>CC</sub> between 0 V and 1.2 V with a transition time of up to 10 msec. From V<sub>CC</sub> = 1.2 V to V<sub>CC</sub> = 3.3 V ± 0.3 V a transition time of 100 µsec is permitted. This parameter is valid for T<sub>amb</sub> = 25 °C only.

- 4. Unused pins at V<sub>CC</sub> or GND.
  5. I<sub>CCZ</sub> is measured with outputs pulled to V<sub>CC</sub> or GND.
  6. This is the bus hold overdrive current required to force the input to the opposite logic state.

# 3.3 V 16-bit inverting buffer/driver (3-State)

### 74LVT16240A

#### **AC CHARACTERISTICS**

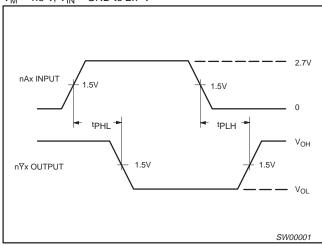
GND = 0 V;  $t_R$  =  $t_F$  = 2.5 ns;  $C_L$  = 50 pF;  $R_L$  = 500  $\Omega$ ;  $T_{amb}$  = -40 °C to +85 °C.

SYMBOL	PARAMETER	WAVEFORM	V <sub>CC</sub>	= 3.3 V ±0.	$V_{CC} = 2.7 \text{ V}$	UNIT	
			MIN	TYP <sup>1</sup>	MAX	MAX	
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay nAx to n <del>Y</del> x	1	0.5 0.5	1.8 2.0	3.2 3.2	4.0 4.0	ns
t <sub>PZH</sub> t <sub>PZL</sub>	Output enable time to HIGH and LOW level	2	1.0 1.0	2.3 2.1	4.0 4.4	5.0 4.8	ns
t <sub>PHZ</sub> t <sub>PLZ</sub>	Output disable time from HIGH and LOW Level	2	1.0 1.0	3.2 3.0	4.5 4.4	5.0 4.8	ns

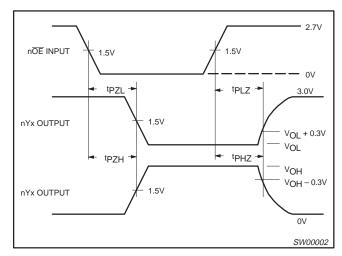
#### NOTE:

#### **AC WAVEFORMS**

 $V_M = 1.5 \text{ V}, V_{IN} = \text{GND to } 2.7 \text{ V}$ 



Waveform 1. Input (nAx) to Output (n $\overline{Y}x$ ) Propagation Delays



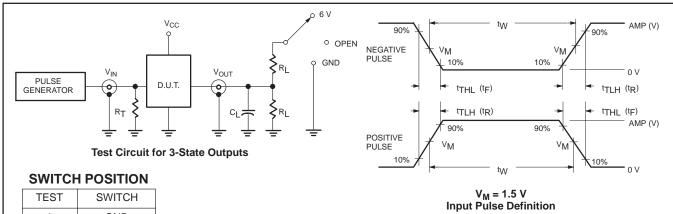
Waveform 2. 3-State Output Enable and Disable Times

<sup>1.</sup> All typical values are at  $V_{CC}$  = 3.3 V and  $T_{amb}$  = 25  $^{\circ}C.$ 

# 3.3 V 16-bit inverting buffer/driver (3-State)

### 74LVT16240A

#### **TEST CIRCUIT AND WAVEFORMS**



TEST	SWITCH
t <sub>PHZ</sub> /t <sub>PZH</sub>	GND
t <sub>PLZ</sub> /t <sub>PZL</sub>	6 V
t <sub>PLH</sub> /t <sub>PHL</sub>	open

#### **DEFINITIONS**

R<sub>L</sub> = Load resistor; see AC CHARACTERISTICS for value.

 $C_L = Load$  capacitance includes jig and probe capacitance; see AC CHARACTERISTICS for value.

 $R_T = Termination$  resistance should be equal to  $Z_{OUT}$  of pulse generators.

FAMILY	INPUT PULSE REQUIREMENTS										
FAIVIILT	Amplitude Rep. Rate		t <sub>W</sub>	t <sub>R</sub>	t <sub>F</sub>						
74LVT16	2.7 V	≤10 MHz	500 ns	≤2.5 ns	≤2.5 ns						

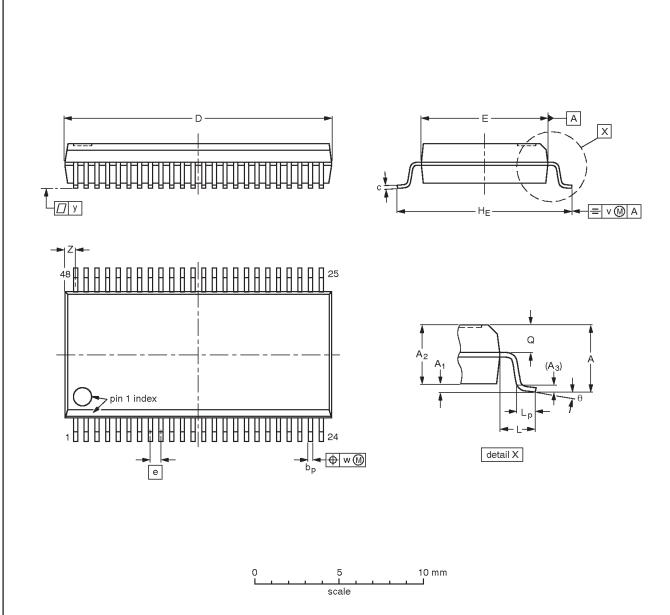
SW00003

# 3.3 V 16-bit inverting buffer/driver (3-State)

### 74LVT16240A

### SSOP48: plastic shrink small outline package; 48 leads; body width 7.5 mm

SOT370-1



#### **DIMENSIONS (mm are the original dimensions)**

UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	A <sub>3</sub>	bp	c	D <sup>(1)</sup>	E <sup>(1)</sup>	е	HE	L	Lp	Q	٧	w	у	Z <sup>(1)</sup>	θ
mm	2.8	0.4 0.2	2.35 2.20	0.25	0.3 0.2	0.22 0.13	16.00 15.75	7.6 7.4	0.635	10.4 10.1	1.4	1.0 0.6	1.2 1.0	0.25	0.18	0.1	0.85 0.40	8° 0°

#### Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

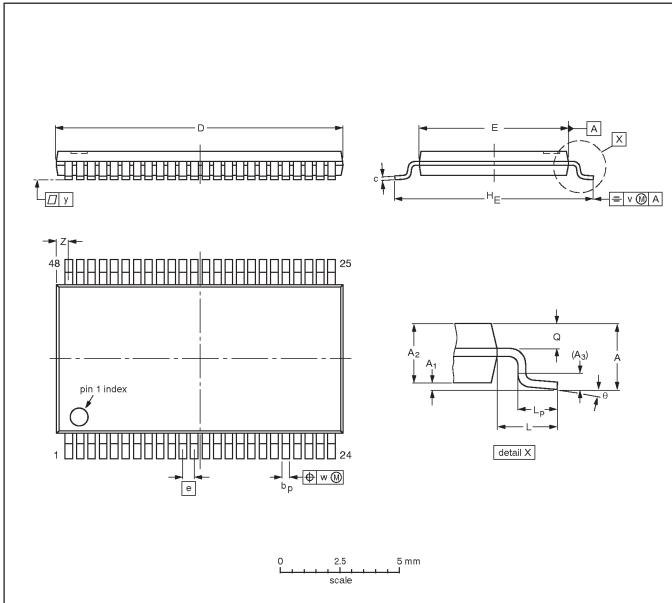
OUTLINE			REFER	EUROPEAN	ISSUE DATE			
VERSI	ON	IEC	JEDEC	EIAJ		PROJECTION	1330E DATE	
SOT37	<b>'</b> 0-1		MO-118				<del>-95-02-04-</del> 99-12-27	

# 3.3 V 16-bit inverting buffer/driver (3-State)

### 74LVT16240A

### TSSOP48: plastic thin shrink small outline package; 48 leads; body width 6.1 mm

SOT362-1



#### DIMENSIONS (mm are the original dimensions).

UNIT	A max.	Α1	A <sub>2</sub>	А3	bp	c	D <sup>(1)</sup>	E <sup>(2)</sup>	е	HE	L	Lp	Q	٧	w	у	Z	θ
mm	1.2	0.15 0.05	1.05 0.85	0.25	0.28 0.17	0.2 0.1	12.6 12.4	6.2 6.0	0.5	8.3 7.9	1	0.8 0.4	0.50 0.35	0.25	0.08	0.1	0.8 0.4	8° 0°

#### Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	EIAJ		PROJECTION	1330E DATE	
SOT362-1		MO-153				<del>-95-02-10-</del> 99-12-27	

### 3.3 V 16-bit inverting buffer/driver (3-State)

74LVT16240A

#### REVISION HISTORY

Rev	Date	Description
_3	20030221	Product data (9397 750 11152); ECN 853-1776 29438); supersedes product specification of 1998 Feb 19 (9397 750 03547).
		Modifications:
		Ordering information table on page 2 corrected: remove 'North America' column.
		"Logic symbol (IEEE/IEC)" on page 3 modified to correct pin names.
_2	19980219	Product specification (9397 750 03547); ECN 853–1776 18990; supersedes data of 1994 Dec 15.

#### **Data sheet status**

Level	Data sheet status <sup>[1]</sup>	Product status <sup>[2] [3]</sup>	Definitions
I	Objective data	Development	This data sheet contains data from the objective specification for product development.  Philips Semiconductors reserves the right to change the specification in any manner without notice.
II	Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
III	Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN).

<sup>[1]</sup> Please consult the most recently issued data sheet before initiating or completing a design.

#### **Definitions**

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information — Applications that are described herein for any of these products are for illustrative purposes only. Philips Semiconductors make no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

#### **Disclaimers**

Life support — These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips Semiconductors customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips Semiconductors for any damages resulting from such application.

Right to make changes — Philips Semiconductors reserves the right to make changes in the products—including circuits, standard cells, and/or software—described or contained herein in order to improve design and/or performance. When the product is in full production (status 'Production'), relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN). Philips Semiconductors assumes no responsibility or liability for the use of any of these products, conveys no license or title under any patent, copyright, or mask work right to these products, and makes no representations or warranties that these products are free from patent, copyright, or mask work right infringement, unless otherwise specified.

#### **Contact information**

For additional information please visit

http://www.semiconductors.philips.com. Fax: +31 40 27 24825

For sales offices addresses send e-mail to: sales.addresses@www.semiconductors.philips.com

© Koninklijke Philips Electronics N.V. 2003 All rights reserved. Printed in U.S.A.

Date of release: 02-03

Document order number: 9397 750 11152

Let's make things better.

Philips Semiconductors





<sup>[2]</sup> The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.

<sup>[3]</sup> For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

# **Mouser Electronics**

**Authorized Distributor** 

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

### NXP:

74LVT16240ADG 74LVT16240ADG-T 74LVT16240ADL 74LVT16240ADL-T 74LVT16240ADGG,112 74LVT16240ADGG,118 74LVT16240ADL,112 74LVT16240ADL,118